









	FQD30N06TF_F080	
	Hersteller-Teilenummer:	FQD30N06TF_F080
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET N-CH 60V 22.7A DPAK
<p>Image may be representation. See specs for product details.</p>	Datenblätter:	 FQD30N06TF_F080.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 32363 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	FQD30N06TF_F080
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 22.7A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	32363 pcs Stock
detaillierte Beschreibung	N-Channel 60V 22.7A (Tc) 2.5W (Ta), 44W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	D-Pak
Verlustleistung (max)	2.5W (Ta), 44W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	22.7A (Tc)
Rds On (Max) @ Id, Vgs	45 mOhm @ 11.4A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	945pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)



















































FQD30N06TF_F080 ist neu im Original, Suche FQD30N06TF_F080 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQD30N06TF_F080 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQD30N06TF_F080: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQD30N06TF AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 22.7A DPAK</p>	 <p>FQD30N06TF Fairchild/ON Semiconductor MOSFET N-CH 60V 22.7A DPAK</p>	 <p>FQD30N06TF_F080 Fairchild/ON Semiconductor MOSFET N-CH 60V 22.7A DPAK</p>	 <p>FQD30N06LTM-NL FAIRCHILD FQD30N06LTM-NL FAIRCHILD</p>
 <p>FQD30P06 FAIRCHILD FQD30P06 FAIRCHILD</p>	 <p>FQD380N60 FAIRCHI FAIRCHI TO-252</p>	 <p>FQD30N06LTM Fairchild/ON Semiconductor MOSFET N-CH 60V 24A DPAK</p>	 <p>FQD3N25T FAIRCHILD FQD3N25T FAIRCHILD</p>

heiße Teile

Mehr

 FQD2N60CTF	 FQD2N60CTF-NL	 FQD2N60CTF_F080	 D FQD2N60CTF_F080	 FQD2N60CTM
 FQD2N60CTM	 FQD2N60TM	 D FQD2N60TM	 FQD2N65C	 FQD2N80TM
 FQD2N80TM	 FQD2N80TM-NL	 FQD2N90TF	 FQD2N90TF	 FQD2P25TF
 D FQD2P25TM	 FQD30N06	 FQD30N06L	 FQD30N06LTF	 FQD30N06LTF
 FQD30N06LTM	 FQD30N06LTM	 FQD30N06TF	 FQD30N06TF	 FQD30N06TF_F080
 FQD30N06TM	 FQD30N06TM	 D FQD30P06	 FQD3N25T	 FQD3N30TF
 FQD3N30TF	 D FQD3N30TM	 FQD3N30TM	 FQD3N40TM	 FQD3N40TM
 FQD3N50C	 FQD3N50C/CS	 FQD3N50CTF	 FQD3N50CTF	 FQD3N50CTM
 FQD3N50CTM	 FQD3N60C	 FQD3N60CS	 D FQD3N60CTF	 FQD3N60CTM
 FQD3N60CTM_WS	 FQD3N60TF	 FQD3N60TF	 FQD3N60TM	 FQD3N60TM

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